In re: Jeffry A. Kelber et al.

Serial No.: 10/785,615 Filed: February 24, 2004

Page 4 of 7

REMARKS

Applicants appreciate the thorough examination of the application as evidenced by the Office Action dated August 31, 2006. Claims 28-32 stand rejected under § 102(e) as being anticipated by U.S. Patent No. 6,800,542 to Kim ("Kim") and Claims 33-36 stand rejected under § 102(e) as being anticipated by U.S. Patent Publication No. 2005/0124154 to Park et al. ("Park'). In response, Claim 28 has been amended. Applicants respectfully request reconsideration of the rejections for the reasons that follow.

Claims 28-32 are not anticipated by Kim

Claim 28 recites a conductive structure including:

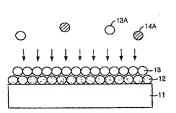
a first conductor;

a plurality of atomic layers of a second conductor directly on the first conductor; and

a first solid material directly on the plurality of atomic layers of the second conductor, remote from the first conductor, the first material being penetrable by the plurality of atomic layers of the second conductor relative to at least a second material other than the second conductor.

Applicants submit that Kim does not disclose at least the underlined portion of independent Claim 28. The Action takes the position that components 13A and 14A are the "first material" and that component 13 is the "plurality of atomic layers of the second conductor." See the Action, page 2. However, in discussing Figure 1B (reproduced below), column 3, lines 47-55 of Kim refers to Figure 1B as follows:

FIG. 1B



As shown in **FIG. 1B**, hydrazine (N_2H_4) 13, which is a reaction gas, is injected ... and ... is reacted with Ru precursor 12 absorbed on the surface of the substrate 11 so that the Ru and volatile by-products, such as HX, NH₃ and N_2 are produced.... [T]he purge gas is injected again in order to remove the volatile by products 14A and a non-reacted hydrazine 13A and a highly pure Ru thin layer is finally deposited.

In re: Jeffry A. Kelber et al.

Serial No.: 10/785,615 Filed: February 24, 2004

Page 5 of 7

Therefore, the by-products **14A** and a non-reacted hydrazine **13A** of Kim, which are removed from the reaction chamber, are <u>a solid material</u> as recited in Claim 28, and Claim 28 is patentable for at least these reasons. Claims 29-32 are patentable at least as depending from patentable Claim 28.

Claims 33-36 are not anticipated by Park

Claim 33 recites a conductive structure including:

a first layer comprising ruthenium;

a second layer comprising a plurality of atomic layers of copper directly on the first layer comprising ruthenium; and

a third layer comprising iodine directly on the second layer comprising a plurality of atomic layers of copper, remote from the first layer comprising ruthenium.

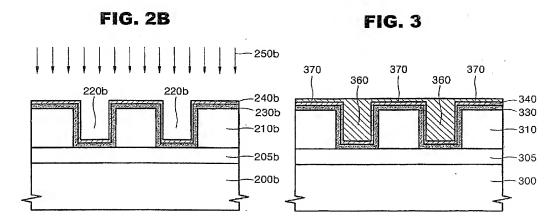
Applicants submit that Park does not disclose various recitations of Claim 33. The Action takes the position that the barrier layer 330 is the "first layer comprising ruthenium" the adhesion layer 340 is the "second layer comprising a plurality of atomic layers of copper," and the layer 370 is the "third layer comprising iodine." *See* the Action, pages 3-4.

Park discusses that the barrier layer 330 may be formed of ruthenium. See Park, paragraph 22. However, Park proposes various materials that could be used as the adhesion layer 340 (also labeled 240a/240b), but does not discuss copper. See paragraph 25 (discussing various materials for the adhesion layer, e.g., ruthenium, rhenium, nickel, palladium, osmium, iridium and platinum, tantalum, tantalum alloys, titanium, titanium alloys, tungsten and tungsten alloys). The layer 360 in Park is described as a copper layer, and the catalyst 250b is identified as iodine. See Park, paragraphs 29-30. However, the layer 360 is not "directly on the first layer comprising ruthenium" as recited in Claim 33 because the adhesion layer 340 in Park is between the ruthenium barrier layer 330 and the copper layer 360.

In re: Jeffry A. Kelber et al. Serial No.: 10/785,615

Filed: February 24, 2004

Page 6 of 7



Additionally, the iodine catalyst **250b** of Park is not directly on the copper layer **360/370** and remote from layers **230** or **240**. Park discusses depositing a copper layer with an iodine or iodine compound as a catalyst. *See* paragraph 13. As shown in **Figures 2B** and 3, the iodine catalyst **250b** is deposited <u>before</u> the copper layer **360/370** so that it is not remote from layers **230** or **240**. As noted in Park in paragraphs 29-30 (emphasis added):

[A] semiconductor substrate 200b, on which an adhesion layer 240b is preformed, is treated with iodine or iodine compound as a catalyst 250b.

Referring to FIG. 3 <u>subsequently</u>, a copper layer 360 is formed using (hfac)Cu(vtms) as a copper precursor on the surface of an adhesion layer 340 by using said chemical vapor deposition method.

Therefore, Park does not teach or suggest a "third layer comprising iodine directly on the second layer comprising a plurality of atomic layers of copper, remote from the first layer comprising ruthenium" as recited in Claim 33, and Claim 33 is patentable for at least these reasons. Claims 34-36 are patentable at least as depending from patentable Claim 33.

Conclusion

Applicants have now shown that Kim does not include a first material that is configured as recited in independent Claim 28, and Park does not include a third layer comprising iodine that is configured as recited in independent Claim 33.

Accordingly, all pending claims are patentable for at least the above reasons, and Applicants respectfully request allowance of the present application.

In re: Jeffry A. Kelber et al. Serial No.: 10/785,615 Filed: February 24, 2004

Page 7 of 7

Respectfully submitted,

Laura M. Kelley Registration No. 48,441 Attorney for Applicants

Customer Number 20792

Myers Bigel Sibley & Sajovec, P.A. P.O. Box 37428 Raleigh, NC 27627 919-854-1400 919-854-1401 (Fax)

CERTIFICATION OF ELECTRONIC TRANSMISSION UNDER 37 CFR § 1.8

I hereby certify that this correspondence is being transmitted electronically to the U.S. Patent and Trademark Office on November 29, 2006.

Carey Gregory

Date of Signature: November 29, 2006